











SN54AHC540, SN74AHC540

SCLS260M - DECEMBER 1995-REVISED MAY 2016

SNx4AHC540 Octal Buffers/Drivers With 3-State Outputs

Features

- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.

2 Applications

- Servers
- PCs and Notebooks
- **Network Switches**
- Wearable Health and Fitness Devices
- Telecom Infrastructures
- Electronic Points of Sale

3 Description

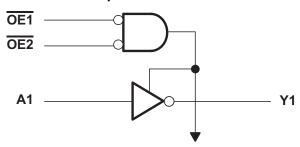
The SNx4AHC540 octal buffers/drivers are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

Device Information⁽¹⁾

PART NUMBER	PACKAGE (PINS)	BODY SIZE (NOM)
SN74AHC540N	PDIP (20)	25.40 mm × 6.35 mm
SN74AHC540DB	SSOP (20)	7.50 mm × 5.30 mm
SN74AHC540PW	TSSOP (20)	6.50 mm × 4.40 mm
SN74AHC540DGV	TVSOP (20)	5.00 mm × 4.40 mm
SN74AHC540DW	SOIC (20)	12.80 mm × 7.50 mm
SNJ54AHC540FK	LCCC (20)	9.0 mm x 9.0 mm
SNJ54AHC540W	CFP (20)	13.72 mm x 8.13 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic



To Seven Other Channels



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	hanges from Revision L (October 2015) to Revision M	Page
•	Updated front page Simplified Schematic diagram	1
•	Updated Pin Out drawing diagrams to new standard	4
•	Updated Functional Block Diagram	
 Updated front page Simplified Schematic diagram Updated Pin Out drawing diagrams to new standard Updated Functional Block Diagram Updated Outputs in Function Table of Device Functional Modes section Changes from Revision K (September 2014) to Revision L Added junction temperature Updated the Handling Ratings table to an ESD Ratings table and move the storage temperature to the Absolute Maximum Ratings table Corrected the Overview to state that the outputs provide non-inverted data 	10	
C	hanges from Revision K (September 2014) to Revision L	Page
•	Added junction temperature	8
•	Updated the Handling Ratings table to an ESD Ratings table and move the storage temperature to the Absolute Maximum Ratings table	{
•	Corrected the Overview to state that the outputs provide non-inverted data	10
<u>•</u>	Added Community Resources	13
C	hanges from Revision J (July 2003) to Revision K	Page





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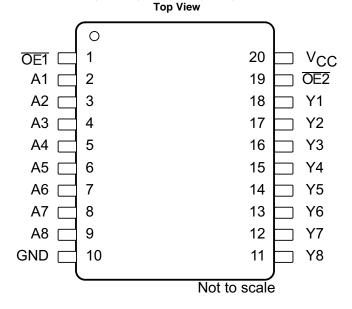
•	Added $T_A = -40^{\circ}$ C to 125°C for SN74AHC540 in both Switching Characteristics tables	. 7
•	Added Typical Characteristics.	. 8
•	Added Detailed Description section	10
•	Added Application and Implementation section	11
•	Added Power Supply Recommendations and Layout sections.	12

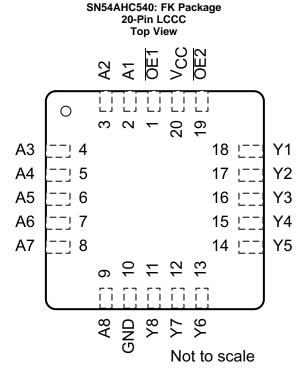
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5 Pin Configuration and Functions

SN54AHC540: J or W Package; SN74AHC540: DB, DGV, DW, N, NS, or PW Package SN54AHC540: 20-Pin CDIP or CFP; SN74AHC540: 20-Pin SSOP, TVSOP, SOIC, PDIP, PDIP, or TSSOP





Pin Functions

PIN		1/0	DESCRIPTION				
NO.	NAME	I/O	DESCRIPTION				
1	OE1	I	Output Enable 1				
2	A1	I	A1 Input				
3	A2	I	A2 Input				
4	A3	1	A3 Input				
5	A4	1	A4 Input				
6	A5	I	A5 Input				
7	A6	I	A6 Input				
8	A7	I	A7 Input				
9	A8	1	A8 Input				
10	GND	_	Ground				
11	Y8	0	Y8 Output				
12	Y7	0	Y7 Output				
13	Y6	0	Y6 Output				
14	Y5	0	Y5 Output				
15	Y4	0	Y4 Output				
16	Y3	0	Y3 Output				
17	Y2	0	Y2 Output				
18	Y1	0	Y1 Output				
19	OE2	I	Output Enable 2				
20	V _{CC}	_	Power Pin				



Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range (2)		-0.5	7	V
Vo	Output voltage range (2)		-0.5	$V_{CC} + 0.5$	V
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through V _{CC} or GN	D		±75	mA
T_{J}	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
	Floatrootatia	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	1000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	2000	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			SN54AHC540		SN74AH	LINUT		
			MIN	MAX	MIN	MAX	UNIT	
V _{CC}	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
V_{IH}	High-level input voltage	$V_{CC} = 3 V$	2.1		2.1		V	
		$V_{CC} = 5.5 \text{ V}$	3.85		3.85			
		V _{CC} = 2 V		0.5		0.5		
V _{IL}	Low-level Input voltage	V _{CC} = 3 V		0.9		0.9	V	
		$V_{CC} = 5.5 \text{ V}$		1.65		1.65		
VI	Input voltage		0	5.5	0	5.5	V	
Vo	Output voltage		0	V _{CC}	0	V _{CC}	V	
		V _{CC} = 2 V		-50		-50	μA	
I _{OH}	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		-4	mA	
		$V_{CC} = 5 V \pm 0.5 V$		-8		-8		
		V _{CC} = 2 V		50		50	μA	
I_{OL}	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4	Α	
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA	
01/0	Langet toward for the confell and a	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	A /	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20		20	ns/V	
T _A	Operating free-air temperature	1	-55	125	-40	125	°C	

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

Product Folder Links: SN54AHC540 SN74AHC540

The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information

		SN74AHC540							
THERMAL METRIC ⁽¹⁾		DB (SSOP)	DGV (TVSOP)	DW (SOIC)	N (PDIP)	NS (PDIP)	PW (TSSOP)	UNIT	
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	99.9	119.2	83.0	54.9	80.4	105.4	°C/W	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	61.7	34.5	48.9	41.7	46.9	39.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	55.2	60.7	50.5	35.8	47.9	56.4	°C/W	
ΤυΨ	Junction-to-top characterization parameter	22.6	1.2	21.1	27.9	19.9	3.1	°C/W	
ΨЈВ	Junction-to-board characterization parameter	54.8	60.0	50.1	35.7	47.5	55.8	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC} T _A = 25°C		С	SN54AHC540		SN74AHC540		-40°C to 125°C SN74AHC540		UNIT	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		2 V	1.9	2		1.9		1.9		1.9		
	$I_{OH} = -50 \ \mu A$	3 V	2.9	3		2.9		2.9		2.9		
V _{OH}		4.5 V	4.4	4.5		4.4		4.4		4.4		V
	I _{OH} = -4 mA	3 V	2.58			2.48		2.48		2.48		
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		3.8		
		2 V			0.1		0.1		0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1		0.1	
V_{OL}		4.5 V			0.1		0.1		0.1		0.1	V
	I _{OH} = 4 mA	3 V			0.36		0.5		0.44		0.44	
	I _{OH} = 8 mA	4.5 V			0.36		0.5		0.44		0.44	
I _I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1 ⁽¹⁾		±1		±1	μΑ
I _{OZ} ⁽²⁾	$V_O = V_{CC}$ or GND $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V			±0.2 5		±2.5		±2.5		±2.5	μΑ
Icc	$V_I = V_{CC}$ or $I_O = 0$	5.5 V			4		40		40		40	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		2	10				10			pF
Co	$V_O = V_{CC}$ or GND	5 V		4								рF

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$. (2) For input and output pins, I_{OZ} includes the input leakage current.



6.6 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C		SN54AHC540		SN74AHC540		T _A = -40°C to 125°C SN74AHC540		UNIT				
	(INFO1)	(001701)	CAFACITANCE	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX					
t _{PLH}	Α	Υ	C 45 p C	4.8(1)	7 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	9.5					
t _{PHL}	A	ĭ	$C_L = 15 pF$	4.8 ⁽¹⁾	7 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	9.5	ns				
t _{PZH}	ŌĒ	V	0 45 - 5	6.8(1)	10.5 ⁽¹⁾	1 ⁽¹⁾	12.5 ⁽¹⁾	1	12.5	1	13.5					
t _{PZL}	OE	Y	Y	$C_L = 15 pF$	6.8 ⁽¹⁾	10.5 ⁽¹⁾	1 ⁽¹⁾	12.5 ⁽¹⁾	1	12.5	1	13.5	ns			
t _{PHZ}	ŌĒ		0 15 5	6.8 ⁽¹⁾	10.5 ⁽¹⁾	1 ⁽¹⁾	12.5 ⁽¹⁾	1	12.5	1	13.5					
t _{PLZ}	OE	Y	Y	Y	Y	$C_L = 15 pF$	τ	6.8 ⁽¹⁾	10.5 ⁽¹⁾	1 ⁽¹⁾	12.5 ⁽¹⁾	1	12.5	1	13.5	ns
t _{PLH}	^	Υ	0 50-5	7.3	10.5	1	12	1	12	1	13.5					
t _{PHL}	Α	Y	$C_L = 50 pF$	7.3	10.5	1	12	1	12	1	13.5	ns				
t _{PZH}	ŌĒ	Y	0 50-5	8	14	1	16	1	16	1	17					
t _{PZL}	OE	Y	$C_L = 50 pF$	8	14	1	16	1	16	1	17	ns				
t _{PHZ}	ŌĒ	Y	C 50 7 5	8	15.4	1	17.5	1	17.5	1	18.5					
t _{PLZ}	UE	Y	$C_L = 50 \text{ pF}$	8	15.4	1	17.5	1	17.5	1	18.5	ns				
t _{sk(o)}			C _L = 50 pF		1.5 ⁽²⁾				1.5			ns				

On products compliant to MIL-PRF-38535, this parameter is not production tested. On products compliant to MIL-PRF-38535, this parameter does not apply.

6.7 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM			FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C		SN54A	SN54AHC540 SN7		HC540	T _A = -40°C to 125°C SN74AHC540		UNIT							
	(INPUT)	(001701)	CAPACITANCE	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX											
t _{PLH}	۸	Y	0 45 -5	3.7 ⁽¹⁾	5 ⁽¹⁾	1 ⁽¹⁾	6 ⁽¹⁾	1	6	1	7											
t _{PHL}	Α	Y	$C_L = 15 pF$	3.7 ⁽¹⁾	5 ⁽¹⁾	1 ⁽¹⁾	6 ⁽¹⁾	1	6	1	7	ns										
t _{PZH}	ŌĒ	Y	0 45 -5	4.7 ⁽¹⁾	7.2 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	9.5											
t _{PZL}	OE	OE Y	Y	Y	Y	Y	Y	Y	Y	ť	ť	Y	$C_L = 15 pF$	4.7 ⁽¹⁾	7.2(1)	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	9.5	ns
t _{PHZ}	ŌĒ	Y	0 45 -5	4.5 ⁽¹⁾	6.8 ⁽¹⁾	1 ⁽¹⁾	8 ⁽¹⁾	1	8	1	8.5											
t _{PLZ}	OE	Y	C _L = 15 pF	4.5 ⁽¹⁾	6.8 ⁽¹⁾	1 ⁽¹⁾	8 ⁽¹⁾	1	8	1	8.5	ns										
t _{PLH}	۸	Y	C	5.2	7	1	8	1	8	1	9											
t _{PHL}	Α	ĭ	$C_L = 50 pF$	5.2	7	1	8	1	8	1	9	ns										
t _{PZH}	ŌĒ	Y	0 50-5	6.2	9.2	1	10.5	1	10.5	1	11.5											
t _{PZL}		Y	Y	Y	Y	Y	Y	Y	$C_L = 50 pF$	6.2	9.2	1	10.5	1	10.5	1	11.5	ns				
t _{PHZ}		ŌĒ	V	C	6	8.8	1	10	1	10	1	10.5										
t _{PLZ}	UE	Υ	ť	ť	ť	Y	Y	ť	Ť	$C_L = 50 \text{ pF}$	6	8.8	1	10	1	10	1	10.5	ns			
t _{sk(o)}			C _L = 50 pF		1 ⁽²⁾				1			ns										

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

On products compliant to MIL-PRF-38535, this parameter does not apply.



6.8 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$

	PARAMETER	SN74AH0	LINUT	
	PARAMETER	MIN	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V _{OL}		8.0	V
$V_{OL(V)}$	Quiet output, minimum dynamic V _{OL}		-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V _{OH}	4.7		V
$V_{IH(D)}$	High-level dynamic input voltage	3.5		V
$V_{IL(D)}$	Low-level dynamic input voltage		1.5	V

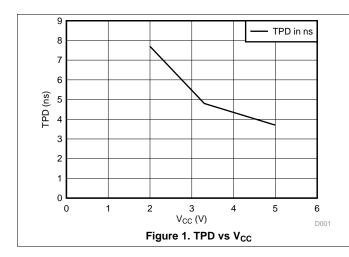
⁽¹⁾ Characteristics are for surface-mount packages only.

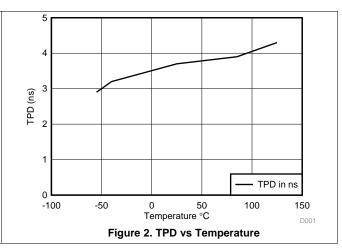
6.9 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST C	CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	12	pF

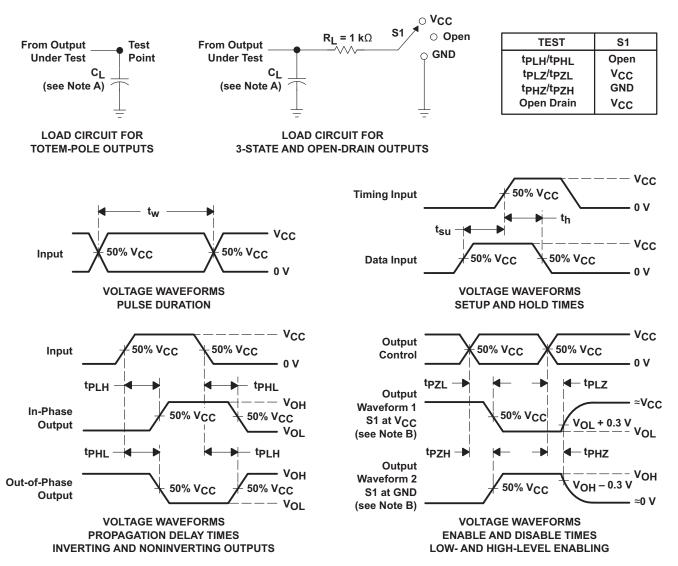
6.10 Typical Characteristics







7 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_Q = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



8 Detailed Description

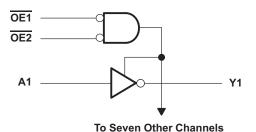
8.1 Overview

The SNx4AHC540 octal buffers/drivers are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

The 3-state control gate is a two-input AND gate with active-low inputs. If either output-enable ($\overline{\text{OE1}}$ or $\overline{\text{OE2}}$) input is high, all corresponding outputs are in the high-impedance state. The outputs provide inverted data when they are not in the high-impedance state.

OE should be tied to V_{CC} through a pullup resistor to ensure the high-impedance state during power up or power down. The minimum value of the resistor is determined by the current-sinking capability of the driver.

8.2 Functional Block Diagram



8.3 Feature Description

SNx4AHC540 device has a wide operating voltage range and operates from 2 V to 5.5 V. The inputs accept voltages up to 5.5 V, which allows for down translation. Slow input edges and low drive will minimize output overshoots and undershoots.

8.4 Device Functional Modes

Table 1 shows the device functions for each buffer and driver.

Table 1. Function Table (Each Buffer/Driver)

	INPUTS	OUTPUT	
OE1	OE2	Α	Υ
L	L	L	Н
L	L	Н	L
Н	Х	Х	Hi-Z
Х	Н	Х	Hi-Z



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The SN74AHC540 is a low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs accept voltages up to 5.5 V, which allows down translation to the V_{CC} level. Figure 5 shows how the slower edges can reduce ringing on the output compared to higher drive parts like AC.

9.2 Typical Application

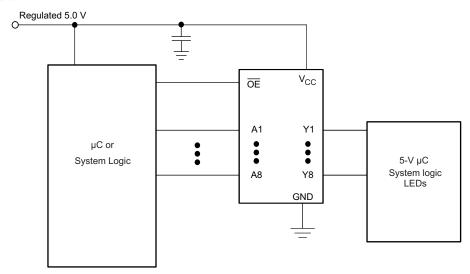


Figure 4. Typical Application Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- Recommended Input Conditions:
 - For rise time and fall time specifications, see $\Delta t/\Delta V$ in the *Recommended Operating Conditions* table.
 - For specified high and low levels, see V_{IH} and V_{IL} in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid $V_{\text{CC.}}$
- 2. Recommended Output Conditions:
 - Load currents should not exceed 25 mA per output and 75 mA total for the part.
 - Outputs should not be pulled above V_{CC}.

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TEXAS INSTRUMENTS

Typical Application (continued)

9.2.3 Application Curve

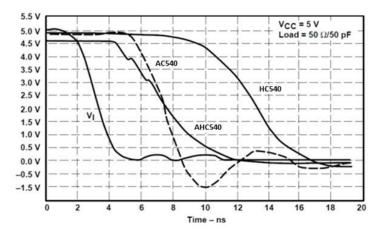


Figure 5. Switching Characteristics Comparison

10 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended. If there are multiple V_{CC} terminals then 0.01 μ F or 0.022 μ F is recommended for each power terminal. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

10.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in the Figure 6 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC}, whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

11 Layout

11.1 Layout Example

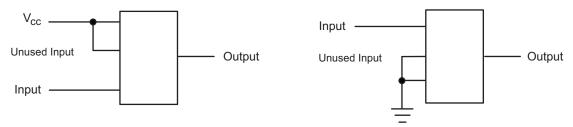


Figure 6. Layout Diagram



12 Device and Documentation Support

12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHC540	Click here	Click here	Click here	Click here	Click here
SN74AHC540	Click here	Click here	Click here	Click here	Click here

12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9685001Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9685001Q2A SNJ54AHC 540FK	Samples
5962-9685001QSA	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9685001QS A SNJ54AHC540W	Samples
SN74AHC540DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA540	Samples
SN74AHC540DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA540	Samples
SN74AHC540DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC540	Samples
SN74AHC540DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC540	Samples
SN74AHC540N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC540N	Samples
SN74AHC540PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA540	Samples
SN74AHC540PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA540	Samples
SN74AHC540PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA540	Samples
SNJ54AHC540FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9685001Q2A SNJ54AHC 540FK	Samples
SNJ54AHC540W	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9685001QS A SNJ54AHC540W	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. **PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

PACKAGE OPTION ADDENDUM



24-Aug-2018

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AHC540, SN74AHC540:

Catalog: SN74AHC540

Military: SN54AHC540

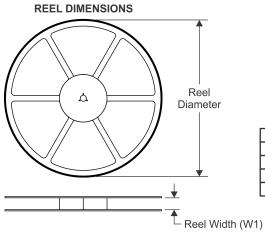
NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 11-Jan-2016

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All differsions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC540DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHC540DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC540DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHC540PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

www.ti.com 11-Jan-2016



*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC540DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74AHC540DGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74AHC540DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHC540PWR	TSSOP	PW	20	2000	367.0	367.0	38.0

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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